Description

RENESAS

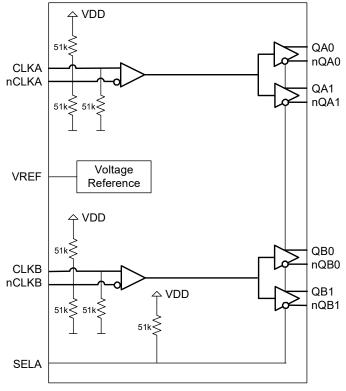
The 8P34S2102 is a high-performance, low-power, differential dual 1:2 LVDS output, 1.8V fanout buffer. The device is designed for the fanout of high-frequency, very low additive phase-noise clock and data signals.

Two independent buffer channels are available. Each channel has two low-skew outputs. High isolation between channels minimizes noise coupling. AC characteristics such as propagation delay are matched between channels. Guaranteed output-to-output and part-to-part skew characteristics make the 8P34S2102 ideal for those clock distribution applications demanding well-defined performance and repeatability.

The device is characterized to operate from a 1.8V power supply. The integrated bias voltage references enable easy interfacing of AC-coupled signals to the device inputs.

Features

- Dual 1:2 low skew, low additive jitter LVDS fanout buffers
- Matched AC characteristics across both channels
- High isolation between channels
- Low power consumption
- Both differential CLKA, nCLKA and CLKB, nCLKB inputs accept LVDS, LVPECL and single-ended LVCMOS levels
- Maximum input clock frequency: 2GHz
- Output amplitudes: 350mV, 500mV (selectable)
- Output bank skew: 8ps typical
- Output skew: 10ps typical
- Low additive phase jitter, RMS: 45fs typical (f_{REF} = 156.25MHz, 12kHz – 20MHz)
- Full 1.8V supply voltage mode
- Device current consumption (I_{DD}): 76mA typical
- Lead-free (RoHS 6), 16-lead VFQFPN packaging
- -40°C to 85°C ambient operating temperature
- Supports case temperature up to 105°C



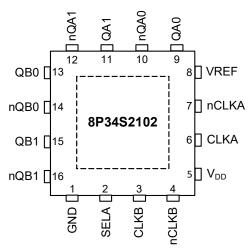
Block Diagram

8P34S2102 transistor count: 293

1

Pin Assignments





Pin Descriptions

Table 1. Pin Descriptions

Number	Name	Type ^[a]	Description
1	GND	Power	Power supply ground.
2	SELA	Input (PU)	Control input. Output amplitude select.
3	CLKB	Input (PD)	Non-inverting differential clock/data input for channel B.
4	nCLKB	Input (PD/PU)	Inverting differential clock/data input for channel B.
5	V _{DD}	Power	Power supply pin.
6	CLKA	Input (PD)	Non-inverting differential clock/data input for channel A.
7	nCLKA	Input (PD/PU)	Inverting differential clock/data input for channel A.
8	VREF	Output	Bias voltage reference for CLKA, nCLKA and CLKB, nCLKB input pairs.
9	QA0	Output	Differential output A0. LVDS interface levels.
10	nQA0	Output	Differential output A0. LVDS interface levels.
11	QA1	Output	Differential output A1. LVDS interface levels.
12	nQA1	Output	Differential output A1. LVDS interface levels.
13	QB0	Output	Differential output B0. LVDS interface levels.
14	nQB0	Output	Differential output B0. LVDS interface levels.
15	QB1	Output	Differential output B1. LVDS interface levels.
16	nQB1	Output	Differential output B1. LVDS interface levels.
ePad	GND_EPAD	Power	Exposed pad of package. Connect to ground.

[a] Pull-up (PU) and pull-down (PD) resistors are indicated in parentheses. *Pull-up* and *pull-down* refers to internal input resistors. See Table 4, *DC Input Characteristics,* for typical values.

Function Tables

Table 2. SELA Output Amplitude Selection Table

SELA	QA, QB Output Amplitude (mV)
0	350
1 (default)	500

Absolute Maximum Ratings

The absolute maximum ratings are stress ratings only. Stresses greater than those listed below can cause permanent damage to the device. Functional operation of the 8P34S2102 at absolute maximum ratings is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Table 3. Absolute Maximum Ratings

Item	Rating
Supply voltage, V _{DD}	4.6V
Inputs, V _I	-0.5V to V _{DD} + 0.5V
Outputs, I _O Continuous current Surge current	10mA 15mA
Input sink/source, I _{REF}	±2mA
Maximum Junction Temperature, T _{J,MAX}	125°C
Storage Temperature, T _{STG}	-65°C to 150°C
ESD - Human Body Model ^[a]	2000V
ESD - Charged Device Model ^[a]	1500V

[a] According to JEDEC JS-001-2012/JESD22-C101E.

DC Electrical Characteristics

Table 4. DC Input Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C _{IN}	Input capacitance			2		pF
R _{PULLDOWN}	Input pull-down resistor			51		kΩ
R _{PULLUP}	Input pull-up resistor			51		kΩ

Table 5. Power Supply DC Characteristics, V_{DD} = 1.8V ± 5%, T_A = -40°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V _{DD}	Power supply voltage			1.71	1.8	1.89	V
	Power supply	QA[0:1], QB[0:1] outputs	500mV amplitude		93	120	mA
I _{DD}	current	terminated 100Ω between nQx, Qx	350mV amplitude		76	96	mA

Table 6. LVCMOS Inputs DC Characteristics, V_{DD} = 1.8V ± 5%, $T_{\textrm{A}}$ = -40°C to 85°C

Symbol	Param	eter	Test Conditions	Minimum	Typical	Maximum	Units
V _{IH}	Input high voltage	SELA		$0.65 \cdot V_{DD}$		V _{DD} + 0.3	V
V _{IL}	Input low voltage	SELA		-0.3		$0.35 \cdot V_{DD}$	V
I _{IH}	Input high current	SELA	V _{IN} = V _{DD} = 1.89V			10	μA
I _{IL}	Input low current	SELA	V _{IN} = 0V, V _{DD} = 1.89V	-150			μA

Table 7. Differential Inputs Characteristics, V_{DD} = 1.8V \pm 5%, $T_{\rm A}$ = -40°C to 85°C

Symbol	Param	eter	Test Conditions	Minimum	Typical	Maximum	Units
I _{IH}	Input high current	CLKA, nCLKA CLKB, nCLKB	V _{IN} = V _{DD} = 1.89V			150	μA
L.	Input low current	CLKA, CLKB	V _{IN} = 0V, V _{DD} = 1.89V	-10			μA
IIL III		nCLKA, nCLKB	V _{IN} = 0V, V _{DD} = 1.89V	-150			μA
VREF	Reference voltage ^[a]		I _{REF} = +100μA, V _{DD} = 1.8V	0.9		1.30	V

[a] VREF specification is applicable to the AC-coupled input interfaces shown in Figure 5 and Figure 6.

Table 8. LVDS DC Characteristics, V_{DD} = 1.8V ± 5%, $T_{\rm A}$ = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
ΔV_{OD}	V _{OD} Magnitude Change				50	mV
ΔV_{OS}	V _{OS} Magnitude Change				50	mV

AC Electrical Characteristics

Table 9. AC Electrical Characteristics, V_{DD} = 1.8V ± 5%, T_A = -40°C to 85°C ^[a]

Symbol	Paramete	er	Test Conditions	Minimum	Typical	Maximum	Units
f _{REF}	Input frequency					2	GHz
$\Delta V / \Delta t$	Input edge rate			1.5			V/ns
t _{PD}	Propagation dela	ay ^{[b], [c]}	CLKA to any QAx, CLKB to any nQBx	100	225	400	ps
<i>t</i> sk(o)	Output skew ^{[d], [6}	e]			10	30	ps
<i>t</i> sk(b)	Output bank ske	w ^{[e], [f]}			8	25	ps
<i>t</i> sk(p)	Pulse skew ^[g]		f _{REF} = 100MHz		5	20	ps
<i>t</i> sk(pp)	Part-to-part skew	/ [e], [h]				200	ps
4	Buffer Additive P Jitter, RMS;		f _{REF} = 156.25MHz; Integration range: 1kHz – 40MHz		60	75	fs
t _{JIT}	500mV amplitude; refer to Additive Phase Jitter		f _{REF} = 156.25MHz square wave, V _{PP} = 1V; Integration range: 12kHz – 20MHz		45	55	fs
$\Phi_{\sf N}(\geq$ 30M)	Clock single-side band phase noise		≥30MHz offset from carrier and noise floor		< -160		dBc/Hz
+	Spurious suppression, coupling between channels		f_{QA} = 491.52MHz, f_{QB} = 61.44MHz; measured between neighboring outputs		-71		dB
t _{JIT, SP}			f_{QA} = 491.52MHz, f_{QB} = 15.36MHz; measured between neighboring outputs		-82		dB
+ /+	Output rise/ fall t	imo	10% to 90%, outputs loaded with 100 Ω		220	400	ps
t _R / t _F			20% to 80%, outputs loaded with 100Ω		110	250	ps
V _{PP}	Input voltage amplitude	CLKA, CLKB		0.15		1.2	V
V _{PP_DIFF}	Differential input voltage amplitude	CLKA, CLKB		0.3		2.4	V
V _{CMR}	Common mode input voltage ^[i]			1.1		$V_{DD} - (V_{PP/2})$	V
M	Differential		SELA = 0, outputs loaded with 100Ω	247	350	454	mV
V _{OD}	output voltage		SELA = 1, outputs loaded with 100Ω	300	500	650	mV
M	Offectiveliers		SELA = 0		0.77		V
V _{OS}	Offset voltage		SELA = 1		0.68		V

[a] Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

[b] Measured from the differential input crossing point to the differential output crossing point.

[c] Input V_{PP} = 400mV.

[d] Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at the differential cross points.

[e] This parameter is defined in accordance with JEDEC Standard 65.

[f] Defined as skew within a bank of outputs at the same voltage and with equal load conditions.

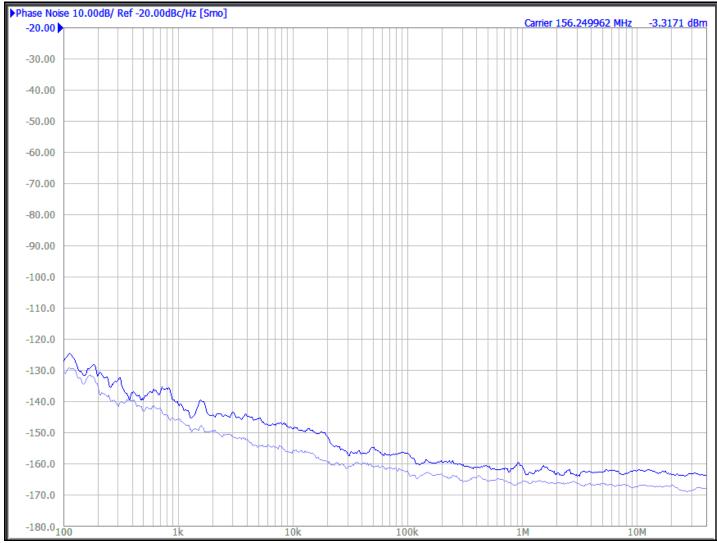
SSB Phase Noise dBc/Hz

- [g] Output pulse skew is the absolute value of the difference of the propagation delay times: $|t_{PLH} t_{PHL}|$.
- [h] Defined as skew between outputs on different devices operating at the same supply voltage, same frequency, same temperature and with equal load conditions. Using the same type of inputs on each device, the outputs are measured at the differential cross points.
- [i] Common Mode Input Voltage is defined as the cross-point voltage.

Additive Phase Jitter

The spectral purity in a band at a specific offset from the fundamental compared to the power of the fundamental is called the *dBc Phase Noise*. This value is normally expressed using a Phase noise plot and is most often the specified plot in many applications. Phase noise is defined as the ratio of the noise power present in a 1Hz band at a specified offset from the fundamental frequency to the power value of the fundamental. This ratio is expressed in decibels (dBm) or a ratio of the power in the 1Hz band to the power in the fundamental. When the required offset is specified, the phase noise is called a *dBc* value, which simply means dBm at a specified offset from the fundamental. By investigating jitter in the frequency domain, we get a better understanding of its effects on the desired application over the entire time record of the signal. It is mathematically possible to calculate an expected bit error rate given a phase noise plot.

Figure 2. Additive Phase Jitter. Frequency: 156.25MHz, Integration range: 12kHz to 20MHz = 45fs typical



Offset from Carrier Frequency (Hz)

As with most timing specifications, phase noise measurements have issues relating to the limitations of the measurement equipment. The noise floor of the equipment can be higher or lower than the noise floor of the device. Additive phase noise is dependent on both the noise floor of the input source and measurement equipment. Measured using a Wenzel 156.25MHz Oscillator as the input source.

Applications Information

Recommendations for Unused Input and Output Pins

Inputs

CLK/nCLK Inputs

For applications not requiring the use of the differential input, both CLK and nCLK can be left floating. Though not required, but for additional protection, a $1k\Omega$ resistor can be tied from CLK to ground.

Outputs

LVDS Outputs

All unused LVDS output pairs can be either left floating or terminated with 100Ω across. If they are left floating there should be no trace attached.

VREF

The unused VREF pin can be left floating. We recommend that there is no trace attached.

Wiring the Differential Input to Accept Single-Ended Levels

Figure 3 shows an example of how a differential input can be wired to accept single ended levels. To satisfy the VCMR requirement, the reference voltage V1 is set to 1.2V which is generated by the bias resistors R1 and R2. The bypass capacitor (C1) is used to help filter noise on the DC bias. This bias circuit should be located as close to the input pin as possible. The ratio of R1 and R2 might need to be adjusted to position the V1 to meet the VCRM requirement. For example, if the input clock swing is 1.8V and VDD = 1.8V, R1 and R2 value should be adjusted to set V1 at 1.2V in this example. The values below are for when both the single ended swing and VDD are at the same voltage. This configuration requires that the sum of the output impedance of the driver (Ro) and the series resistance (Rs) equals the transmission line impedance. In addition, matched termination at the input will attenuate the signal in half. This can be done in one of two ways. First, R3 and R4 in parallel should equal the transmission line impedance and the signal DC offset after AC coupling should be equal to V1, i.e. 1.2V in this example. For most Zo=50 Ω applications, R3=75 Ω and R4 can be 130 Ω . By keeping the same R3/R4 ratio, the values of the resistors can be increased to reduce the loading for slower and weaker LVCMOS driver. When using single-ended signaling, the noise rejection benefits of differential signaling are reduced. Even though the input can handle larger amplitude signaling, it is recommended that the amplitude be reduced. For single-ended applications, the swing can be larger. Make sure the single ended logic high and logic low signal operates within specification limit. Though some of the recommended components might not be used, the pads should be placed in the layout. They can be utilized for debugging purposes. The datasheet specifications are characterized and guaranteed by using a differential signal.

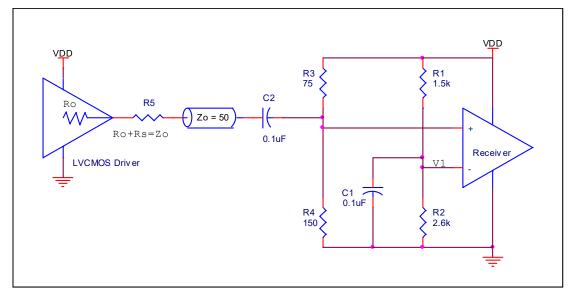


Figure 3. Example Schematic for Wiring a Differential Input to Accept Single-ended Levels

1.8V Differential Clock Input Interface

The CLK /nCLK accepts LVDS, LVPECL and other differential signals. The differential input signal must meet both the V_{PP} and V_{CMR} input requirements. *Figure 4 to Figure 6* show interface examples for the CLK /nCLK input driven by the most common driver types. The input interfaces suggested here are examples only. If the driver is from another vendor, use their termination recommendation. Please consult with the vendor of the driver component to confirm the driver termination requirements.



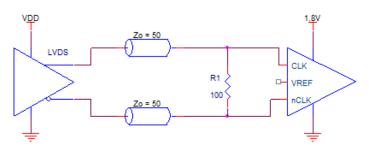
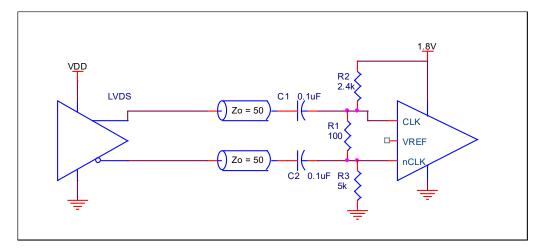
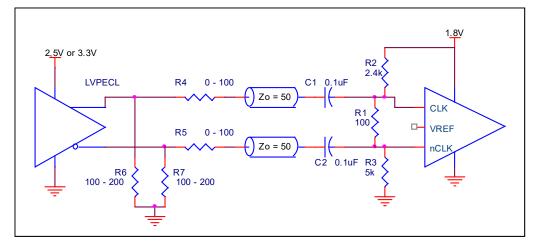


Figure 5. Differential Input Driven by an LVDS Driver-AC Coupling







LVDS Driver Termination

For a general LVDS interface, the recommended value for the termination impedance (Z_T) is between 90 Ω and 132 Ω . The actual value should be selected to match the differential impedance (Z_0) of your transmission line. A typical point-to-point LVDS design uses a 100 Ω parallel resistor at the receiver and a 100 Ω differential transmission-line environment. In order to avoid any transmission-line reflection issues, the components should be surface mounted and must be placed as close to the receiver as possible. Renesas offers a full line of LVDS compliant devices with two types of output structures: current source and voltage source.

The standard termination schematic as shown in *Figure* 7 can be used with either type of output structure. *Figure* 8, which can also be used with both output types, is an optional termination with center tap capacitance to help filter common mode noise. The capacitor value should be approximately 50pF. If using a non-standard termination, it is recommended to contact Renesas and confirm if the output structure is current source or voltage source type. In addition, since these outputs are LVDS compatible, the input receiver's amplitude and common-mode input range should be verified for compatibility with the output.

Figure 7. Standard LVDS Termination

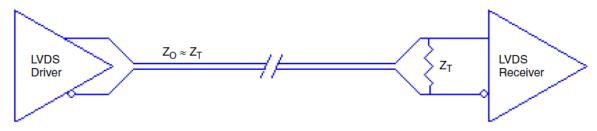
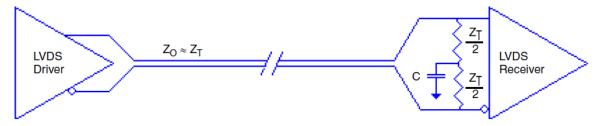


Figure 8. Optional LVDS Termination



VFQFN EPAD Thermal Release Path

In order to maximize both the removal of heat from the package and the electrical performance, a land pattern must be incorporated on the Printed Circuit Board (PCB) within the footprint of the package corresponding to the exposed metal pad or exposed heat slug on the package, as shown in *Figure 9*. The solderable area on the PCB, as defined by the solder mask, should be at least the same size/shape as the exposed pad/slug area on the package to maximize the thermal/electrical performance. Sufficient clearance should be designed on the PCB between the outer edges of the land pattern and the inner edges of pad pattern for the leads to avoid any shorts.

While the land pattern on the PCB provides a means of heat transfer and electrical grounding from the package to the board through a solder joint, thermal vias are necessary to effectively conduct from the surface of the PCB to the ground plane(s). The land pattern must be connected to ground through these vias. The vias act as "heat pipes". The number of vias (i.e. "heat pipes") are application specific and dependent upon the package power dissipation as well as electrical conductivity requirements. Thus, thermal and electrical analysis and/or testing are recommended to determine the minimum number needed. Maximum thermal and electrical performance is achieved when an array of vias is incorporated in the land pattern. It is recommended to use as many vias connected to ground as possible. It is also recommended that the via diameter should be 12 to 13mils (0.30 to 0.33mm) with 1oz copper via barrel plating. This is desirable to avoid any solder wicking inside the via during the soldering process which may result in voids in solder between the exposed pad/slug and the thermal land. Precautions should be taken to eliminate any solder voids between the exposed heat slug and the land pattern. Note: These recommendations are to be used as a guideline only.

For more information, refer to the application note on the Surface Mount Assembly of Amkor's Thermally/ Electrically Enhance Leadframe Base Package, Amkor Technology.

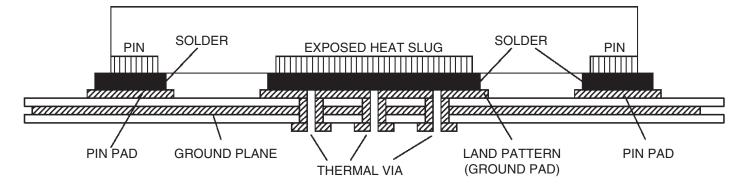


Figure 9. P.C. Assembly for Exposed Pad Thermal Release Path - Side View (drawing not to scale)

Case Temperature Considerations

This device supports applications in a natural convection environment which does not have any thermal conductivity through ambient air. The printed circuit board (PCB) is typically in a sealed enclosure without any natural or forced air flow and is kept at or below a specific temperature. The device package design incorporates an exposed pad (ePad) with enhanced thermal parameters which is soldered to the PCB where most of the heat escapes from the bottom exposed pad. For this type of application, it is recommended to use the junction-to-board thermal characterization parameter Ψ_{JB} (Psi-JB) to calculate the junction temperature (T_J) and ensure it does not exceed the maximum allowed junction temperature in the Absolute Maximum Rating table.

The junction-to-board thermal characterization parameter, Ψ_{JB} is calculated using the following equation:

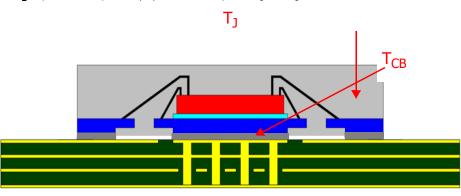
$T_J = T_{CB} + \Psi_{JB} \times P_{D}$, where

 T_J = Junction temperature at steady state condition in (^oC).

T_{CB} = Case temperature (Bottom) at steady state condition in (°C).

 Ψ_{JB} = Thermal characterization parameter to report the difference between junction temperature and the temperature of the board measured at the top surface of the board.

 P_D = power dissipation (W) in desired operating configuration.



The ePad provides a low thermal resistance path for heat transfer to the PCB and represents the key pathway to transfer heat away from the IC to the PCB. It's critical that the connection of the exposed pad to the PCB is properly constructed to maintain the desired IC case temperature (T_{CB}). A good connection ensures that temperature at the exposed pad (T_{CB}) and the board temperature (T_B) are relatively the same. An improper connection can lead to increased junction temperature, increased power consumption and decreased electrical performance. In addition, there could be long-term reliability issues and increased failure rate.

Example Calculation for Junction Temperature (T_J): T_J = T_{CB} + Ψ _{JB} x P_D

Package type	16 VFQFN
Body size (mm)	3 x 3 x 0.9
ePad size (mm)	1.7 x 1.7
Thermal Via	2 x 2 Matrix
Ψ _{JB}	1.3°C/W
T _{CB}	105°C
P _D	0.21W

For the variables above, the junction temperature is equal to 105.3°C. Since this is below the maximum junction temperature of 125°C, there are no long term reliability concerns. In addition, since the junction temperature at which the device was characterized using forced convection is 119°C, this device can function without the degradation of the specified AC or DC parameters.

Power Considerations

This section provides information on power dissipation and junction temperature for the 8P34S2102. Equations and example calculations are also provided.

1. Power Dissipation.

The following is the power dissipation for V_{DD} = 1.8V + 5% = 1.89V, which gives worst case results.

Maximum current at 85°C: $V_{DD MAX}$ = 112mA.

Power_MAX = V_{DD MAX} * I_{DD MAX} = 1.89V * 112mA = 211.68mW

2. Junction Temperature.

Junction temperature, Tj, is the temperature at the junction of the bond wire and bond pad directly affects the reliability of the device. The maximum recommended junction temperature is 125°C. Limiting the internal transistor junction temperature, Tj, to 125°C ensures that the bond wire and bond pad temperature remains below 125°C.

The equation for Tj is as follows: Tj = θ_{JA} * Pd_total + T_A

Tj = Junction Temperature

 θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming no air flow and a multi-layer board, the appropriate value is 74.7°C/W per Table 10 below.

Therefore, Tj for an ambient temperature of 85°C with all outputs switching is:

85°C + 0.21168W * 74.7°C/W = 100.8°C. This is below the limit of 125°C.

This calculation is only an example. Tj will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (multi-layer).

Table 10. Thermal Resistance θ_{JA} for 16-lead VFQFN, Forced Convection

θ _{JA} (°C/W) vs. Air Flow (m/s)				
Meters per Second	0	1	2	
16-lead VFQFN Multi-Layer PCB, JEDEC Standard Test Boards	74.7	65.3	58.5	

Package Outline Drawings

The package outline drawings are appended at the end of this document and are accessible from the link below. The package information is the most current data available.

www.idt.com/us/en/document/psc/16-vfqfpn-package-outline-drawing30-x-30-x-09-mm-05-mm-170-x-170-mm-epad-nlnlg16p2

Marking Diagram

•	• Line 1: "XXX" indicates the last three characters of the Asm lot number.
XXX	• Line 2:
YWW\$ \$2021	 "YWW" indicates the date code (Y is the last digit of the year, and "WW" is a work week number that the part was assembled.
	• "\$": mark code.

• Line 3 indicates the truncated part number.

Ordering Information

Table 11. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
8P34S2102NLGI	S202I		Tray	
8P34S2102NLGI8	S202I	16-lead VFQFN, Lead-Free	Tape & Reel, Pin 1 Orientation: EIA-481-C	-40°C to 85°C
8P34S2102NLGI/W	S202I		Tape & Reel, Pin 1 Orientation: EIA-481-D/E	

Table 12. Pin 1 Orientation in Tape and Reel Packaging

Part Number Suffix	Pin 1 Orientation	Illustration	
8	Quadrant 1 (EIA-481-C)	Consci PIN 10RENTATION CARRIER TAPE TOPSDE (Round Sprocker Holes)	
/W	Quadrant 2 (EIA-481-D/E)	Correct PIN 1 ORIENTATION CARRIER TAPE TOP SIDE (Round Sprocket Holes)	

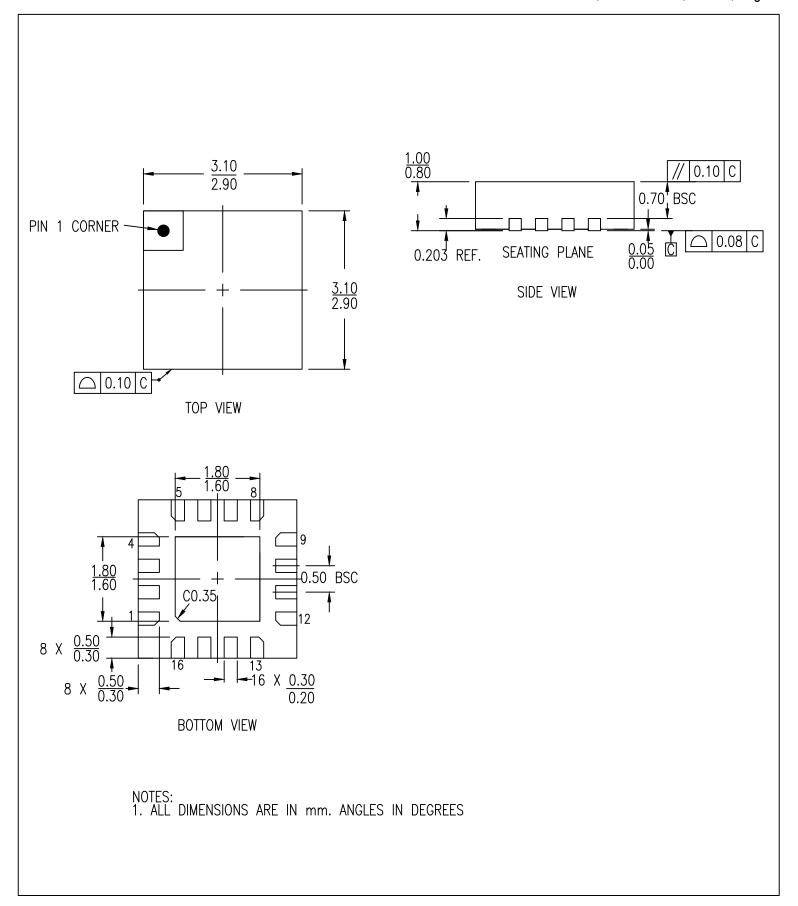
Revision History

Revision Date	Description of Change	
September 8, 2020	Updated the section Wiring the Differential Input to Accept Single-Ended Levels.	
	 Updated Figures 3, 5 and 6. Reformatted document template. 	
September 21, 2017	Updated the package outline drawings; however, no mechanical changes	
	Completed other minor improvements	
October 20, 2016	Initial datasheet.	

RENESAS

16-VFQFPN Package Outline Drawing

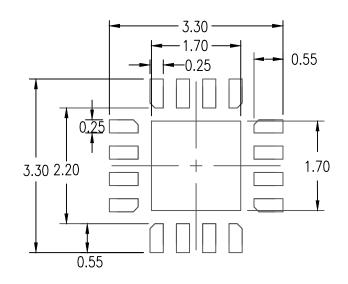
3.0 x 3.0 x 0.9 mm, 0.5mm Pitch, 1.70 x 1.70 mm Epad NL/NLG16P2, PSC-4169-02, Rev 05, Page 1





16-VFQFPN Package Outline Drawing

3.0 x 3.0 x 0.9 mm, 0.5mm Pitch, 1.70 x 1.70 mm Epad NL/NLG16P2, PSC-4169-02, Rev 05, Page 2



RECOMMENDED LAND PATTERN DIMENSION

NOTES:

- 1. ALL DIMENSIONS ARE IN mm. ANGLES IN DEGREES
- 2. TOP DOWN VIEW-AS VIEWED ON PCB
- 3. LAND PATTERN RECOMMENDATION IS PER IPC-7351B GENERIC REQUIREMENT FOR SURFACE MOUNT DESIGN AND LAND PATTERN

Package Revision History				
Date Created Rev No. Description				
Oct 25, 2017	Rev 04	Remove Bookmak at Pdf Format & Update Thickness Tolerance		
Jan 18, 2018	Rev 05	Change QFN to VFQFPN		

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Corporate Headquarters

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